

#### **REGULATORY COMPLIANCE**











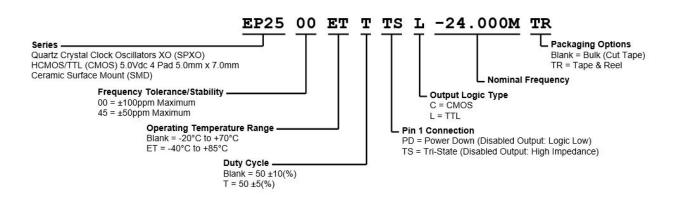
#### **ITEM DESCRIPTION**

Quartz Crystal Clock Oscillators XO (SPXO) HCMOS/TTL (CMOS) 5.0Vdc 4 Pad 5.0mm x 7.0mm Ceramic Surface Mount (SMD)

ELECTRICAL SPECIFICA	TIONS
Nominal Frequency	1MHz to 125MHz
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range,Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration ±100ppm Maximum ±50ppm Maximum
Aging at 25°C	±5ppm/year Maximum
Operating Temperature Range	-20°C to +70°C -40°C to +85°C
Supply Voltage	5.0Vdc ±10%
Input Current	Unloaded 45mA Maximum
Output Voltage Logic High (V <sub>OH</sub> )	IOH = -16mA Vdd-0.4Vdc Minimum at Output Logic Type of CMOS 2.4Vdc Minimum at Output Logic Type of TTL
Output Voltage Logic Low (V <sub>OL</sub> )	IOL = +16mA 0.4Vdc Maximum
Rise/Fall Time	4nSec Maximum (Measured at 20% to 80% of waveform) at Output Logic Type of CMOS 4nSec Maximum (Measured at 0.8Vdc to 2.0Vdc) at Output Logic Type of TTL
Duty Cycle	Measured at 1.4Vdc with TTL Load or 50% of waveform with HCMOS Load 50 ±10(%) 50 ±50(%) (Not available with TTL Output Logic Type over Nominal Frequency range of 27.000001MHz to 125MHz; Not available with CMOS Output Logic Type over Nominal Frequency range of 50.000001MHz to 125MHz)
Load Drive Capability	50pF HCMOS Load Maximum (over 1MHz to 50MHz at CMOS Output Logic Type) 15pF HCMOS Load Maximum (over 50.000001MHz to 125MHz at CMOS Output Logic Type) 10TTL Load Maximum over 1MHz to 40MHz at TTL Output Logic Type 5TTL Load Maximum over 40.000001MHz to 125MHz at TTL Output Logic Type
Output Logic Type	CMOS TTL
Pin 1 Connection	Power Down (Disabled Output: Logic Low) Tri-State (Disabled Output: High Impedance)
Pin 1 Input Voltage (Vih and Vil)	+2.0Vdc Minimum to enable output, +0.8Vdc Maximum to disable output, No Connect to enable output.
Standby Current	50μA Maximum (Pin 1 = Ground, Disabled Output: Logic Low)
Disable Current	30mA Maximum (Pin 1 = Ground, Disabled Output: High Impedance)
Absolute Clock Jitter	±250pSec Maximum, ±100pSec Typical over Nominal Frequency of 1MHz to 33MHz ±100pSec Maximum, ±50pSec Typical over Nominal Frequency of 33.000001MHz to 125MHz
One Sigma Clock Period Jitter	±50pSec Maximum over Nominal Frequency of 1MHz to 33MHz ±30pSec Maximum over Nominal Frequency of 33.000001MHz to 125MHz
Start Up Time	10mSec Maximum
Storage Temperature Range	-55°C to +125°C

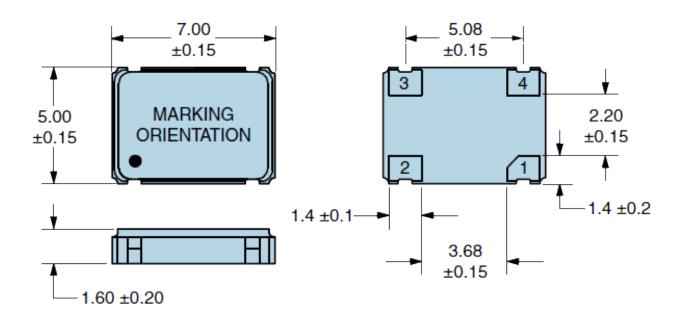


#### **PART NUMBERING GUIDE**

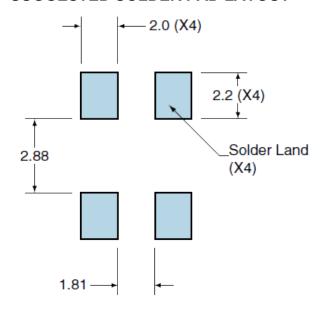




#### **MECHANICAL DIMENSIONS**



#### SUGGESTED SOLDER PAD LAYOUT



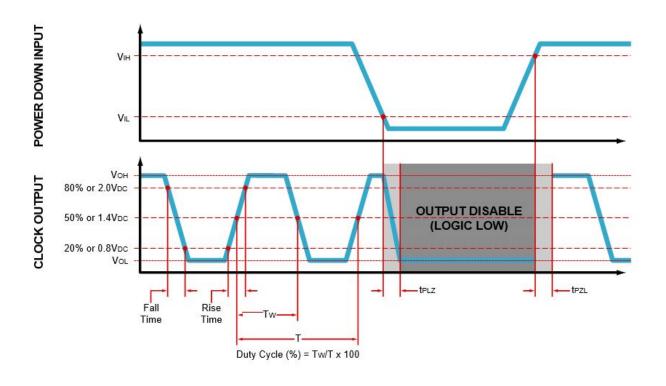
PIN	CONNECTION
1	Power Down Or Tri-State
2	Ground/Case Ground
3	Output
4	Supply Voltage

All Tolerances are ±0.1

#### **All Dimensions in Millimeters**

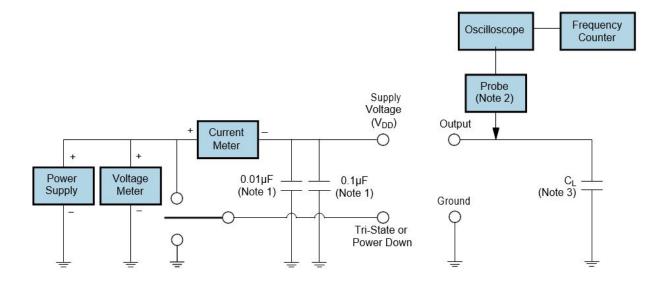


#### **OUTPUT WAVEFORM & TIMING DIAGRAM**





#### **TEST CIRCUIT FOR CMOS OUTPUT**



Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less Than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low input capacitance (<12pF), 10X Attentuation Factor, High Impedance (>10Mohms), and High bandwidth (>300MHz) Passive probe is recommended.

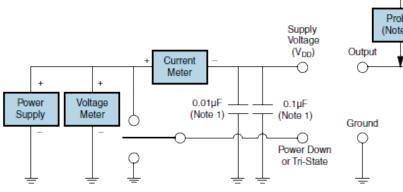
Note 3: Capacitance value CL includes sum of all probe and fixture capacitance. See applicable specification sheet for 'Load Drive Capability'.

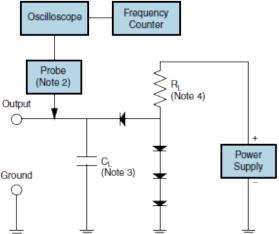


#### **TEST CIRCUIT FOR TTL OUTPUT**

Output Load Drive Capability	R <sub>L</sub> Value (Ohms)	C <sub>L</sub> Value (pF)
10TTL	390	15
5TTL	780	15

Table 1: R<sub>L</sub> Resistance Value and C<sub>L</sub> Capacitance Value Vs. Output Load Drive Capability





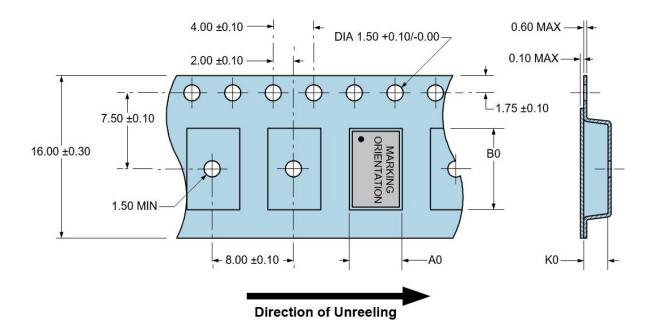
- Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less Than 2mm) to the package ground and supply voltage pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive Probe is recommended.
- Note 3: Capacitance value CL includes sum of all probe and fixture capacitance.
- Note 4: Resistance value RL is shown in Table 1. See applicable specification sheet for 'Load Drive Capability'.
- Note 5: All diodes are MMBD7000, MMBD914, or equivalent.

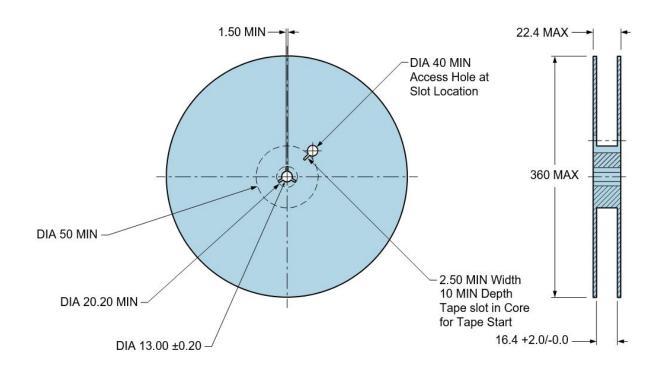


#### **TAPE & REEL DIMENSIONS**

Quantity per Reel: 1,000 Units

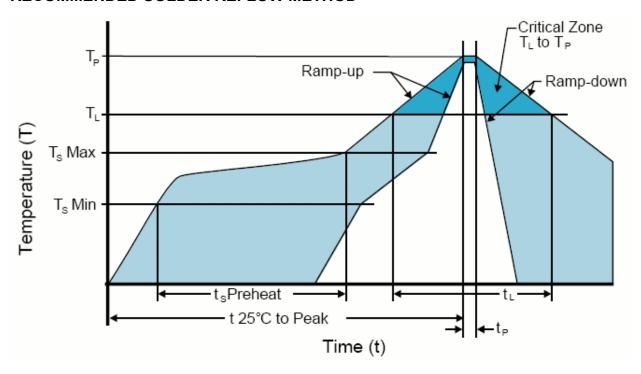
All Dimensions in Millimeters
Compliant to EIA-481







### **RECOMMENDED SOLDER REFLOW METHOD**



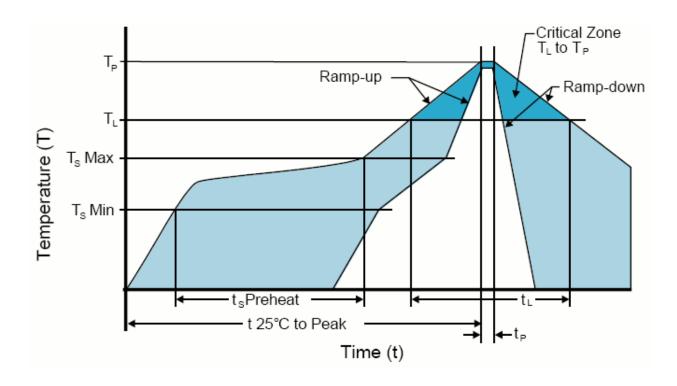
HIGH TEMPERATURE INFRARED/CONVECTION		
T <sub>s</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	3°C/Second Maximum	
Preheat		
- Temperature Minimum (T <sub>S</sub> MIN)	150°C	
- Temperature Typical (T <sub>s</sub> TYP)	175°C	
- Temperature Maximum(T <sub>s</sub> MAX)	200°C	
- Time (t <sub>s</sub> MIN)	60 - 180 Seconds	
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/Second Maximum	
Time Maintained Above:		
- Temperature (T <sub>L</sub> )	217°C	
- Time (t <sub>L</sub> )	60 - 150 Seconds	
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum	
Target Peak Temperature(T <sub>P</sub> Target)	250°C +0/-5°C	
Time within 5°C of actual peak (tp)	20 - 40 Seconds	
Ramp-down Rate	6°C/Second Maximum	
Time 25°C to Peak Temperature (t)	8 Minutes Maximum	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

#### **High Temperature Manual Soldering**

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)



### **RECOMMENDED SOLDER REFLOW METHOD**



LOW TEMPERATURE INFRARED/CONVECTION		
T <sub>s</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/Second Maximum	
Preheat		
- Temperature Minimum (T <sub>S</sub> MIN)	N/A	
- Temperature Typical (T <sub>s</sub> TYP)	150°C	
- Temperature Maximum(T <sub>s</sub> MAX)	N/A	
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds	
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	5°C/Second Maximum	
Time Maintained Above:		
- Temperature (T <sub>L</sub> )	150°C	
- Time (t <sub>∟</sub> )	200 Seconds Maximum	
Peak Temperature (T <sub>P</sub> )	240°C Maximum	
Target Peak Temperature(T <sub>P</sub> Target)	240°C Maximum 2 Times/230°C Maximum 1Time	
Time within 5°C of actual peak (t <sub>P</sub> )	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time	
Ramp-down Rate	5°C/Second Maximum	
Time 25°C to Peak Temperature (t)	N/A	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

### **Low Temperature Manual Soldering**

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)

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